

<u>SOT-89</u>

MAC97A6U

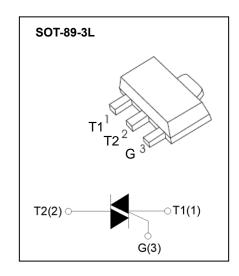
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DESCRIPTION:

The 97A6 triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Package SOT-89 is RoHS compliant.

MAIN FEATURES

100, 1110 1 27 11 01120							
Symbol	Value	Unit					
I _{T(RMS)}	8.0	Α					
V _{DRM} /V _{RRM}	600	V					
I _{GT I} / II / III / IV	5/5/5/10	mA					



MARKING: 97A6

Absolute maximum ratings (Ta=25℃ unless otherwise noted)

Parameter	Symbol	Value		Unit
Repetitive peak off-state voltage	V _{DRM}	600		V
Repetitive peak reverse voltage	V _{RRM}	600		V
RMS on-state current	I _{T(RMS)} 0.8		.8	Α
Non repetitive surge peak on-state current (full cycle, F=50Hz)	Ітѕм	8		А
I²t value for fusing (tp=10ms)	I ² t	0.32		A ² s
Critical rate of rise of on-state current ($I_G = 2 \times I_{GT}$)	dI/dt	I - II -III IV	50 10	- A/μs
Peak gate current	I _{GM}	1		Α
Average gate power dissipation	P _{G(AV)}	0.5		W
Junction Temperature	TJ	-40 ~ +125		$^{\circ}$
Storage Temperature	T _{STG}	-40 ~ +150		$^{\circ}$



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Electrical characteristics (T_A=25 °C, unless otherwise noted)

Parameter	Symbol	Test Condition		Value		Unit
Gate trigger current	I _{GT}	$V_D = 12V I_T = 0.1A$ - $T_j = 25^{\circ}C$	I - II -III	MAX.	5	mA
			IV		10	
Gate trigger voltage	V_{GT}		I - II -III-IV	MAX.	1.2	V
Gate non-trigger voltage	V_{GD}	V _D =V _{DRM} T _j =125℃		MIN.	0.2	V
latching current	IL	$V_D = 12V I_{GT} = 0.1A$ - $T_j = 25^{\circ}C$	I -III-IV	MAX.	10	mA
			II		15	
Holding current	lμ		I - II -III-IV	MAX.	10	mA
Critical-rate of rise	dV/dt	dt $V_D=2/3V_{DRM}$ Gate Open $T_i=12$		MIN.	30	V/µs
of commutation voltage	u v/ut	VD-2/3 V DRM Gate Op				
STATIC CHARACTERISTICS						
Forward "on" voltage	V_{TM}	I _{TM} =0.8A tp=380μs		MAX.	1.7	V
Repetitive Peak Off-State Current	I _{DRM}	VD =VDRM VR =VRRM	T _j =25℃	MAX.	20	μA
Repetitive Peak Reverse Current	I _{RRM}	VD -VDRM VR -VRRM	T _j =125℃	MAX.	100	μA
THERMAL RESISTANCES						
Thermal resistance	Rth(j-c)	Junction to case(AC)		TYP.	60	°C/W
	Rth(j-a)	Junction to ambient		TYP.	150	°C/W







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Typical Characteristics

FIG.1: Maximum power dissipation versus RMS

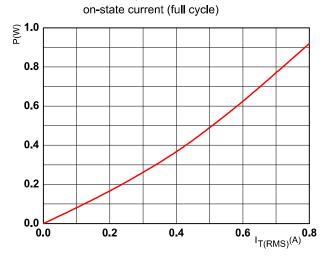


FIG.3: Surge peak on-state current versus number of cycles

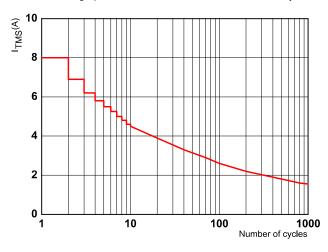


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp < 10ms

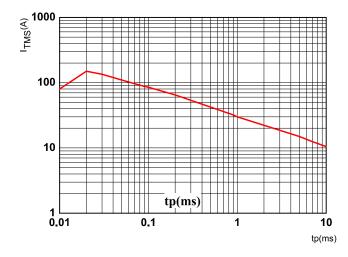


FIG.2: RMS on-state current versus case temperature (full cycle)

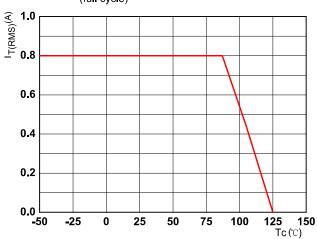


FIG.4: On-state characteristics (maximum values)

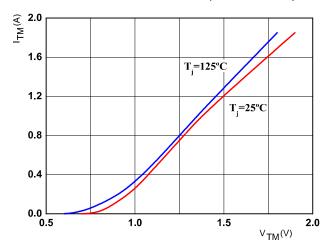


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature (typical values)

